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Electron motion in a (n;1) carbon nanotube is shown to correspond to a de Broglie wave propagating along a helical line on the nanotube wall. This helical motion leads to periodicity of the electron potential energy in the presence of an electric eld normal to the nanotube axis. The period of this potential is proportional to the nanotube radius and is greater than the interatom ic distance in the nanotube. As a result, the behavior of an electron in a (n;1) nanotube subject to a transverse electric eld is similar to that in a semiconductor superlattice. In particular, Bragg scattering of electrons from the long-range periodic potential results in the opening of gaps in the energy spectrum of the nanotube. Modication of the bandstructure is shown to be signicant for experimentally attainable electric elds, which raises the possibility of applying this elect to novel nanoelectronic devices.

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#### I. INTRODUCTION

Carbon nanotubes (CNTs) are cylindrical molecules with nanometer diameter and micrometer length. Since the discovery of CNTs just over a decade ago, their unique electronic and structural properties have aroused great excitement in the scientic community and promise a broad range of applications. Signicant theoretical e orthas been applied to develop rened models of the electronic structure of carbon nanotubes, as well as their optical and transport properties, although even a simple tight-binding model yielding analytic solutions is suicient to elucidate key nanotube features (e.g. whether a CNT of given structure will exhibit metallic or semiconducting properties). In this paper we apply such a model to a particular type of single-wall CNT, a so-called (n;1) nanotube. In Sec. II we show that for such a CNT the electron motion corresponds to a de Broglie wave propagating along a helical line. The theoretical treatment of this type of CNT in an electric eld perpendicular to the nanotube axis (transverse electric eld) can be reduced to a one-dimensional superlattice problem (see Sec. III). Such superlattice behavior of current-carrying electrons suggests the application of CNTs to the development of novel carbon nanotube-based devices.

### II. ENERGY SPECTRUM OF (n;1) NANOTUBES

A single-wall carbon nanotube m ay be considered as a single graphite sheet rolled into a cylinder. The electronic energy spectrum of the CNT is therefore intim ately related to the energy spectrum  $"_{g2D}$  (k) of a two-dim ensional (2D) graphite sheet, which can be written in the tight-binding approximation as  $^2$ :

$$"_{g2D}(k) = {}_{0} \exp \frac{ik_{x}a}{3} + 2 \exp \frac{ik_{x}a}{23} \cos \frac{k_{y}a}{2} ;$$
 (1)

where  $k_x$  and  $k_y$  are the electron wave vector components in the graphite sheet plane along the x and y axes, respectively (see Fig. 1). In the energy spectrum (1), the plus and m inus signs correspond to the conduction and valence bands, respectively, 0 3 eV is the transfer integral between -orbitals of neighboring carbon atoms, and the lattice constant  $a=ja_1j=ja_2j=\sqrt{3}$   $a_{C-C}=2.46\,\mathrm{A}$ , where  $a_1$  and  $a_2$  are the 2D basis vectors and  $a_{C-C}=1.42\,\mathrm{A}$  is the interatomic distance in graphite. The way in which the 2D graphite sheet is rolled up to form the CNT can be described by two vectors, the translation vector T and the chiral vector  $C_h$  (see Fig. 1). The chiral vector  $C_h$  can be expressed in terms of the 2D basis vectors of the unrolled graphite sheet as  $C_h = na_1 + ma_2$ , where the pair of integers (n;m) is used as a standard notation of for a CNT of given crystal structure. To obtain the electronic energy spectrum of the (n;m) CNT, we begin by expressing the wave vector k in terms of components along T and  $C_h$  as  $k = k_k T = T + k_2 C_h = C_h$ , where  $k_k$  and  $k_2$  are subject to the following constraints:  $E_h = T < k_k = T$  and  $E_h = T < T$  and  $E_h = T < T$  are subject to the following constraints:  $E_h = T < T$  and  $E_h = T$ 

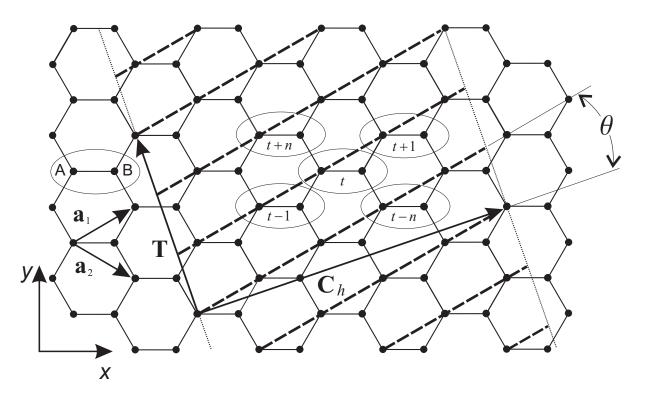


FIG. 1: The unrolled graphite sheet. By connecting the head and tail of the chiral vector  $C_h$  we can construct, for example, a (4;1) carbon nanotube. The dashed lines will then form a helical line on the nanotube wall.

axis and

$$N = \frac{2(n^2 + m^2 + nm)}{d_R};$$
 (2)

The energy spectrum of a (n;m) CNT can be obtained by expressing  $k_x$  and  $k_y$  in terms of  $k_k$  and  $k_2$ , and substituting them in Eq. (1), thus yielding

"= 
$$_{0} \exp \frac{\frac{p}{1} \frac{1}{3a}}{2} k_{k} \cos k \sin + 2 \cos \frac{k_{s}a}{2}$$
; (3)

where we have introduced the new parameter  $k_s = k_2 \cos + k_k \sin$ , and the chiral angle (j j =6) shown in Fig. 1. Taking into account that

$$\cos = \frac{2n + m}{2^{\frac{1}{2}} \frac{p}{n^2 + m^2 + nm}}; \quad \sin = \frac{p}{2^{\frac{1}{2}} \frac{3m}{n^2 + m^2 + nm}}; \tag{4}$$

we have, form 6 0, the equation

P – 3 (
$$k_k cos$$
 k, sin )a = [(2n + m ) $k_s$ a 2k, C<sub>h</sub> ]=m: (5)

Substituting Eqs. (4) and (5) into Eq. (3) we obtain

"= 
$$_{0} \exp i \frac{2n + m}{2m} k_{s} a \frac{k_{?} C_{h}}{m} + 2 \cos \frac{k_{s} a}{2}$$
; (6)

which, together with the constraint  $k_2 = 2$   $1=C_h$ , yields an electron energy spectrum of the form

"= 
$$_0 1 + 4 \cos \frac{k_s a}{2} \cos \frac{2n + m}{2m} k_s a \frac{2l}{m} + 4 \cos^2 \frac{k_s a}{2}$$
: (7)

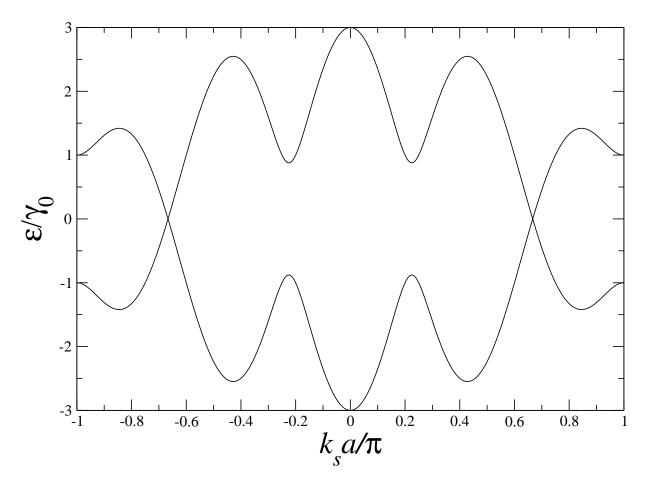


FIG. 2: Electron energy spectrum of a metallic (4;1) CNT as a function of the wave number  $k_{\rm S}$  along a helical line on a nanotube wall.

Form = 1, Eq. (7) becomes independent of 1, and we obtain the electron energy spectrum of a (n;1) CNT in the form

$$\mathbf{v}_{j}(\mathbf{k}_{s}) = (1)^{j} \cdot 1 + 8 \cos \frac{n+1}{2} \mathbf{k}_{s} \mathbf{a} \cos \frac{n \mathbf{k}_{s} \mathbf{a}}{2} \cos \frac{\mathbf{k}_{s} \mathbf{a}}{2};$$
 (8)

where j=1;2 correspond to the valence and conduction bands, respectively. It should be noted that the spectrum (8) depends on the param eter  $k_s$  alone, in contrast to the general case of a (n;m) CNT, for which the electron energy spectrum depends on two parameters  $(k_k$  and  $k_2$  are conventionally used). This peculiarity of a (n;1) CNT is a consequence of its special crystal sym metry: the (n;1) CNT lattice can be obtained by translation of an elementary two-atom cell along a helical line on the nanotube wall (see Fig. 1). As a result, the parameter  $k_s$  has the meaning of an electron wave vector along the helical line, and so any possible electron motion in a (n;1) CNT can be described by a de Broglie wave propagating along such a line. Thus, (n;1) CNTs represent a previously overlooked distinctive class of nanotubes, which may be termed helical nanotubes. The electron energy spectrum of a (4,1) CNT as a function of the helical wave number  $k_s$  is shown in Fig. 2. The band gap for this natotube closes at  $k_s a = 2 = 3$ , and it can be shown that the same is true for all metallic (n;1) nanotubes.

# III. HELICAL NANOTUBES IN A TRANSVERSE ELECTRIC FIELD

Both descriptions of the energy spectrum of a (n;1) CNT  $\mid$  by two parameters,  $k_k$  and  $k_2$ , or a single parameter  $k_s \mid$  are physically equivalent. However, the second description is more convenient for studies of electron processes determined by the above-mentioned helical symmetry of electron motion, and allows one to discover new physical electron electron-electron interaction should be strongly modified for helical one-dimensional motion  $^3$ ). We shall now show that such helical symmetry results in superlattice behavior of a (n;1) CNT in the presence of an electric eld oriented perpendicular to the nanotube axis (a transverse electric eld).

The potential energy of an electron on a helix subject to a transverse electriceld takes the form

$$U = eE R \cos \frac{2 s}{l_0} ; (9)$$

where e is the electron charge, E is the electric eld strength,  $R = C_h = 2$  is the radius of the CNT, s is the electron coordinate along the above-m entioned helical line,

$$l_0 = \frac{2 R}{\cos} = \frac{2a(n^2 + n + 1)}{2n + 1};$$
 (10)

is the length of a single coil of the helix, and the electric potential is assumed to be zero at the axis of the CNT. The potential energy (9) is periodic in the electron coordinates along the helical line and the period of the potential is equal to  $l_0$ . Since this period (10) is proportional to the CNT radius R and is greater than the interatom ic distance  $a_{C-C}$ , the CNT assumes typical superlattice properties. In particular, B ragging rejection of electron waves with wave vectors  $k_s = -\frac{1}{4}$  results in energy splitting within the conduction and valence bands of the CNT. We shall now study this eject in more detail.

In the fram ew ork of the tight-binding m odel, considering only three nearest neighbors to each atom, the wave functions for electron states w ith corresponding energies (8) can be w ritten as

$$_{j}(k_{s}) = \frac{1}{2M} X \qquad _{t}^{(A)} + (1)^{j} \frac{h(k_{s})}{h(k_{s})j} t^{(B)} \exp(ik_{s}ta);$$
 (11)

where M is the total number of two-atom cells in the CNT,  $_{t}^{(A)}$  and  $_{t}^{(B)}$  are -orbital wave functions for the two carbon atom s A and B, respectively, t is the number along the helical line for an elementary cell consisting of these two atom s (see Fig. 1), and h ( $k_s$ ) = 1+ exp( ik\_sa) + exp(ink\_sa). The value of the potential energy U in the external electric eld at the position of a particular atom of the CNT depends on the angle between the electric eld vector and the vector normal to the nanotube axis which passes through this atom. As a consequence, the coordinate of atom A in cell number talong the helical line is

$$s = at + \frac{l_0}{2}$$
: (12)

The angle is de ned in such a way that  $R cos + (n + 1) = (n^2 + n + 1)$  is the coordinate in the direction of the electric eld (with zero at the CNT axis) of atom B in the cell with t = 0. Using Eqs. (11) and (12), we can write the matrix element of the potential energy (9) as

$$h_{i}(k_{s}^{0})_{j}U_{j_{s}^{0}}(k_{s})_{i} = V_{ij}^{+} cos(k_{s}a k_{s}^{0}a + 2 a = l_{0}); 1 + V_{ij} cos(k_{s}a k_{s}^{0}a 2 a = l_{0}); 1;$$

$$(13)$$

w here

$$V_{ij} = \frac{eE R}{4} + (2_{ij} + (2_{ij} + 1)\frac{h(k_s^0)h(k_s)}{h(k_s^0)h(k_s)} \exp \frac{i(n+1)}{n^2+n+1} \exp(i);$$
(14)

and is the K ronecker delta. In the derivation of Eqs. (13) and (14) we have also assumed that the external electric eld E is much less than the atom ic eld, i.e.

$$E = \frac{0}{ea}:$$
 (15)

This allows us to neglect any change in the atom ic wave functions  $_{t}^{(A)}$  and  $_{t}^{(B)}$  due to the eld E, and we take into account only the mixing of states (11) by the eld. A coording to Eq. (13), the eld mixes only electron states (11) with wave vectors diering by  $2 = l_0$ . In this approximation, the exact wave function in the presence of the electric eld,  $_{E}(k_s)$ , can be expressed as a superposition of wave functions (11) with  $k_s$  shifted by integer numbers of  $2 = l_0$ :

To ensure that in Eq. (16) we sum only over dierent electron states, the parameter should be the smallest integer dened by the condition  $_{j}(k_{s}) = _{j}(k_{s} + 2 = l_{0})$ . This condition, together with the 2 =a periodicity of  $_{j}(k_{s})$ ,

implies that  $=l_0==a$ , where is the smallest integer for which this equality is satisted. Using Eq. (10) together with Eq. (2) one can obtain  $=(2n+1)=d_R$ , which yields =N. This result has a transparent physical interpretation, since the two closest carbon atoms equivalent with respect to a translation parallel to the nanotube axis are separated by a distance N a along a helical line.

Substituting the wave function (16) into the Schrodinger equation with the potential energy (9) we obtain a system of equations for the coe cients  $b_i$  entering Eq. (16):

where = 0;1;2;:::;N 1, the index j takes the value 1 or 2 for the valence and conduction bands, respectively, and "<sub>E</sub> ( $k_s$ ) is the electron energy in the presence of the transverse electric eld.

Let us consider the states  $k_s = = \frac{1}{4}$  and  $= \frac{1}{4}$  in the same CNT energy band, which are at the boundaries of a B rillouin zone created by the periodic 'superlattice' potential (9) of the external eld. One should expect the appearance of energy gaps at these values of  $k_s$  due to B ragg rejection of electron waves from the superlattice potential. These states are separated by  $2 = \frac{1}{4}$  and have the same energy, which means that they are strongly mixed by the electric eld. For these values of  $k_s$  it can be shown that the contributions to the sum in Eq. (16) from all other states can be neglected for suiciently weak elds,  $E = \frac{1}{4}$  and  $E = \frac{1}{4}$  are strongly mixed by the electric eld. For these values of  $E = \frac{1}{4}$  and have the same  $E = \frac{1}{4}$  and have the same  $E = \frac{1}{4}$  and  $E = \frac{1}{4}$  and

"= 
$$2 \frac{1}{2} \int_{1}^{2} (\frac{1}{2}) \int_{1}^{2} \int$$

Thus, even a small electric eld results in a superlattice-like change of the electron energy spectrum in (n;1) CNTs, with the appearance of Bragg energy gaps proportional to the eld am plitude E and the nanotube radius R. Notably, this dependence of the Bragg gaps on the external eld and radius applies to any helical quasi-one-dimensional nanostructure in a transverse electric eld: this generic feature arises from the symmetry of the nanostructure, and is independent of the parameters of the tight-binding model used to derive Eq. (18). For example, it should be possible to observe a similar electric recently fabricated InG aAs/G aAs and Si/SiG electron energy spectrum in (n;1) CNTs, with the appearance of Bragg energy gaps proportional to the eld am plitude E and the nanotube radius R. Notably, this dependence of the Bragg gaps on the external eld and radius applies to any helical quasi-one-dimensional nanostructure in a transverse electric eld: this generic feature arises from the symmetry of the nanostructure, and is independent of the parameters of the tight-binding model used to derive Eq. (18). For example, it should be possible to observe a similar electric eld:

It should be emphasized that for single-wall carbon nanotubes the discussed superlattice behavior is a unique feature of (n;1) structures only. For the general case of a (n;m) CNT with m+6 1, the energy spectrum (7) depends on the quantum number 1 in addition to  $k_s$ . As already mentioned, 1 represents the projection of the electron angular momentum on the nanotube axis, and it follows from the corresponding selection rule that the transverse electric eld only mixes electron states with angular momentum 1 and 1 1. For m+6 1, however, states with 1 di ering by one correspond to di erent subbands, and in general have di erent energies for  $k_s = -\frac{1}{6}$ , so that there is no B ragg scattering between these states. The only e ect of the electric eld, therefore, is to mix electron states with di erent energies, which does not lead to noticeable modi cation of the dispersion curves for weak electric elds.

For the particular case of a (1;1) CNT the energy spectrum can be obtained in analytic form for any electron state, since the system of equations (17) consists of four equations only. This system results in a biquadratic equation for the eigenvalues  $"_E$  ( $k_s$ ):

$${}^{*2}_{E}(k_{s}) \qquad {}^{*2}_{E}(k_{s})(w_{1}^{2} + w_{2}^{2} + 2v_{1} + 2v_{2}) + (v_{2} \quad v_{1} + w_{1}w_{2})^{2} = 0;$$
(19)

$$" = \frac{p_{\overline{3}eE \ a}}{2} j\cos(+ = 3) j;$$
 (20)

The result in Eq. (20) can also be obtained from the more general formula (18). It should be noted that the B ragg gap, as well as the whole energy spectrum of the CNT in a transverse electric eld, depends on the orientation of the CNT relative to the eld (i.e. on the angle of rotation ). In particular, when = =6 the B ragg gap (20) is zero:

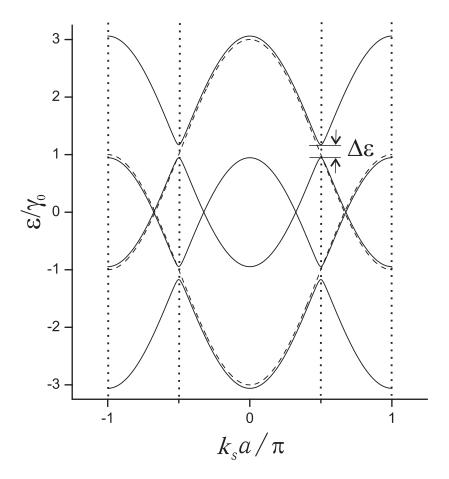


FIG. 3: Electron energy spectrum of a (1;1) CNT in the presence of a transverse electric eld  $E = 0 = (ea_{C-C})$  with E = 0 (solid lines) and without the electric eld (dashed lines). The inner pair of vertical dotted lines indicates the rst Brillouin zone boundary in the presence of the eld, whereas the outer pair corresponds to the rst Brillouin zone boundary without the eld. " is the Bragg gap opened by the electric eld.

for this angle the values of the electric eld potential at atom s A and B in a (1;1) CNT are equal in m agnitude but opposite in sign, and so the mean value of the potential within one elementary cell of the CNT is zero.

In the general case of a (n;1) nanotube, for external electric eld intensities attainable in experiment (E  $10^5$  V/cm) and for a typical nanotube of radius R  $10\,\mathrm{A}$ , the value of the B ragg gap given by (18) is "  $10^{-2}$  eV, which is comparable to the characteristic energy of band splitting in conventional sem iconductor superlattices. As a consequence, the discussed superlattice electric eld in (n;1) CNTs should be observable in experiments, and may take place in existing CNT eld-electric eld in (n;1) CNTs should be observable in experiments, and may take place in existing CNT eld-electric eld in (n;1) CNTs should be a nanotube-based superlattice, with the superlattice period determined by the CNT radius, presents a distinct advantage over sem iconductor superlattices, in which monolayer uctuations are unavoidable. A whole range of new nanoelectronic devices based on the discussed superlattice properties of (n;1) CNTs can be envisaged, including B loch oscillators and quantum cascade lasers. An evaluation of the feasibility of these novel devices and selection of their optimal parameters will undoubtedly form the subject of extensive future research.

#### IV. CONCLUSIONS

In this paper we have discussed a previously overlooked class of CNTs, which may be termed helical nanotubes. While we have concentrated on the superlattice behavior of such nanotubes in a transverse electric eld, we also expect their unique symmetry to manifest itself in modication of the electron-electron, electron-phonon and electron-photon interactions. In addition, we have shown that superlattice behavior in a transverse electric eld is a generic feature of helical quasi-one-dimensional nanostructures, which raises new possibilities for developing optoelectronic devices operating in the terahertz range of frequencies.

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